

Electronic Structure of 2D Hybrid Perovskites: Rashba Spin-Orbit Coupling and Impact of Interlayer Spacing

Meysam Pazoki,^{†a,b} Roghayeh Imani,^{†c} Andreas Röckert,^c and Tomas Edvinsson^{*a}

Supporting Information

^a Department of Materials Science and Engineering, Solid State Physics, Ångström Laboratory, Uppsala University, Box 34, 75121 Uppsala, Sweden.

^b Department of Physics, Shiraz University, Shiraz 71454, Iran.

^c Department of Chemistry, Structural Chemistry, Ångström Laboratory, Uppsala University, Box 538, 75121 Uppsala, Sweden.

[†] These authors contributed equally to this work.

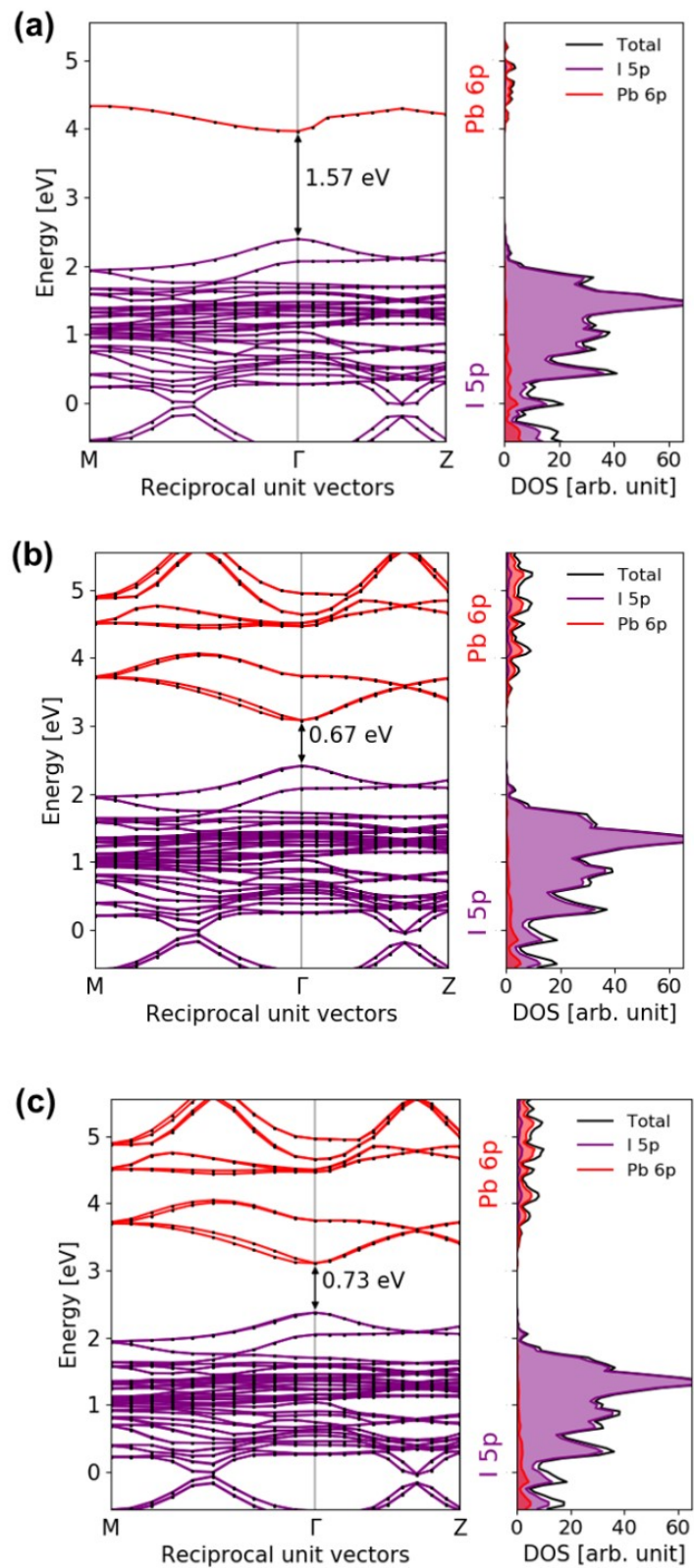


Fig. S1 Calculated band structure and the corresponding partial density of states (PDOS) of MAPbI₃ within: (a) GGA approximation without SOC, core electrons represented by scalar-relativistic pseudopotentials, (b) GGA approximation with SOC, using projected augmented wave functions, (c) GGA approximation with SOC including the van der Waals effects, using projected augmented wave functions.

Table. S1 Lattice parameters of the relaxed structures.

Structure	Method	Lattice parameters		
		a	b	c
BDAPbI ₄	Scalar relativistic	+1.016480934i +0.001094221j -0.011516648k	+0.010714555i +1.055049708j -0.009417520k	+0.453032042i +0.302087656j +1.235248221k
	SOC	+1.016480934i +0.001094221j -0.011516648k	+0.010714555i +1.055049708j -0.009417520k	+0.453032042i +0.302087656j +1.235248221k
	SOC+London	+1.016480934i +0.001094221j -0.011516648k	+0.010714555i +1.055049708j -0.009417520k	+0.453032042i +0.302087656j +1.235248221k
HDAPbI ₄	Scalar relativistic	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +0.7158443164j +0.000000000k	-0.2244716445i +0.000000000j +0.7308821332k
	SOC	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +0.715844316j +0.000000000k	-0.224471644i +0.000000000j +0.730882133k
	SOC+London	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +0.715844316j +0.000000000k	-0.224471644i +0.000000000j +0.730882133k
ODAPbI ₄	Scalar relativistic	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +0.60749364j +0.000000000k	-0.18701i +0.0000j +0.6282k
	SOC	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +0.60749364j +0.000000000k	-0.187010000i +0.000000000j +0.628200000k
	SOC+London	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +0.60749364j +0.000000000k	-0.187010000i +0.000000000j +0.628200000k
DDAPbI ₄	Scalar relativistic	+1.126691658i +0.006270929j +0.100747423k	+0.004816344i +0.599415307j +0.002201466k	-0.150646731i -0.000679544j +0.612748237k
	SOC	+1.126691658i +0.006270929j +0.100747423k	+0.004816344i +0.599415307j +0.002201466k	-0.150646731i -0.000679544j +0.612748237k

	SOC+London	+1.126691658i +0.006270929j +0.100747423k	+0.004816344i +0.599415307j +0.002201466k	-0.150646731i -0.000679544j +0.612748237k
MAPbI₃	Scalar relativistic	+0.988930439i -0.000060348j +0.000218033k	-0.000060722i +0.986392170j -0.000695749k	+0.000307984i -0.000982271j +1.442764694k
	SOC	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +1.000000000j +0.000000000k	+0.000000000i +0.000000000j +1.429581282k
	SOC+London	+1.000000000i +0.000000000j +0.000000000k	+0.000000000i +1.000000000j +0.000000000k	+0.000000000i +0.000000000j +1.429581282k

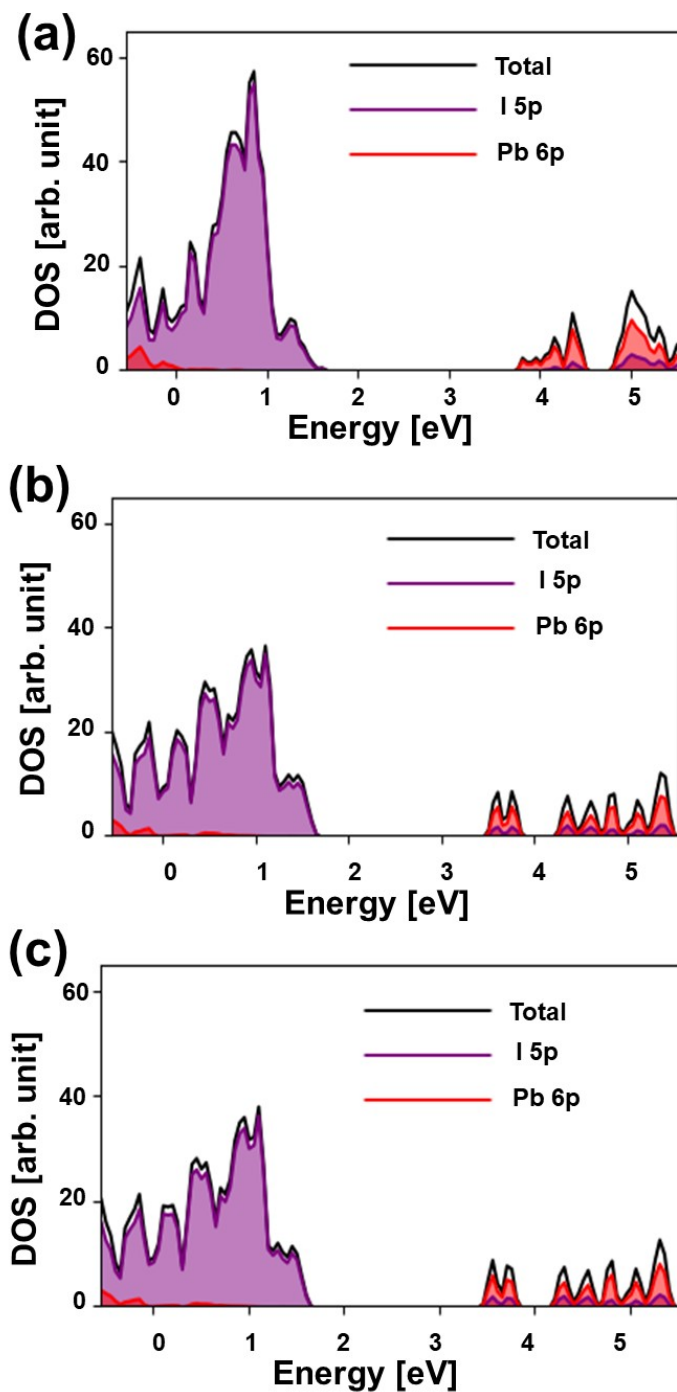


Fig. S2 Calculated total and partial density of states (PDOS) of BDAPbI₄ within: (a) GGA approximation without SOC, core electrons represented by scalar-relativistic pseudopotentials, (b) GGA approximation with SOC, using projected augmented wave functions, (c) GGA approximation with SOC including London dispersion, using projected augmented wave functions.

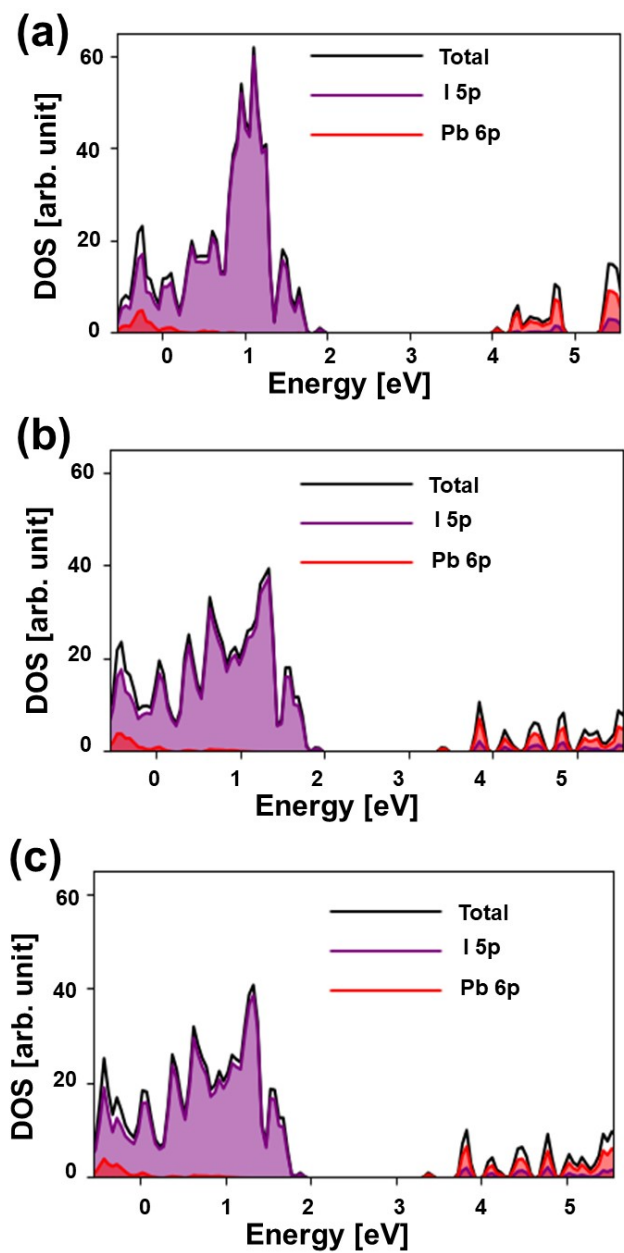


Fig. S3 Calculated total and partial density of states (PDOS) of HDAPbI₄ within: (a) GGA approximation without SOC, core electrons represented by scalar-relativistic pseudopotentials, (b) GGA approximation with SOC, using projected augmented wave functions, (c) GGA approximation with SOC including London dispersion, using projected augmented wave functions.

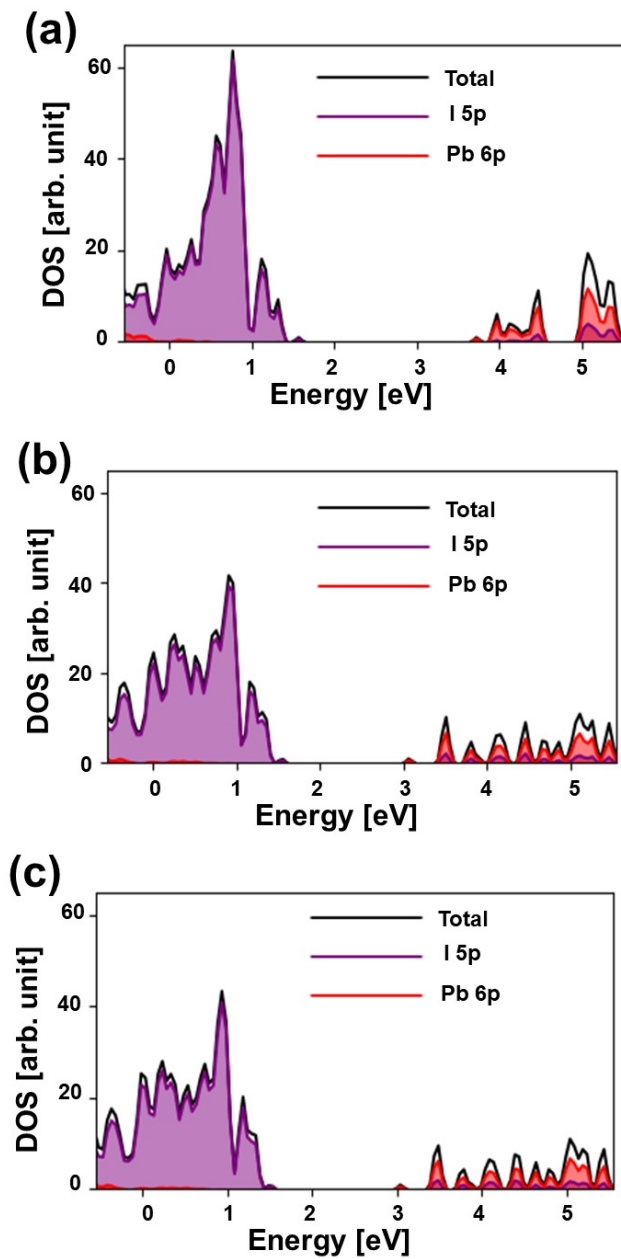


Fig. S4 Calculated total and partial density of states (PDOS) of ODAPbI₄ within: (a) GGA approximation without SOC, core electrons represented by scalar-relativistic pseudopotentials, (b) GGA approximation with SOC, using projected augmented wave functions, (c) GGA approximation with SOC including London dispersion, using projected augmented wave functions.

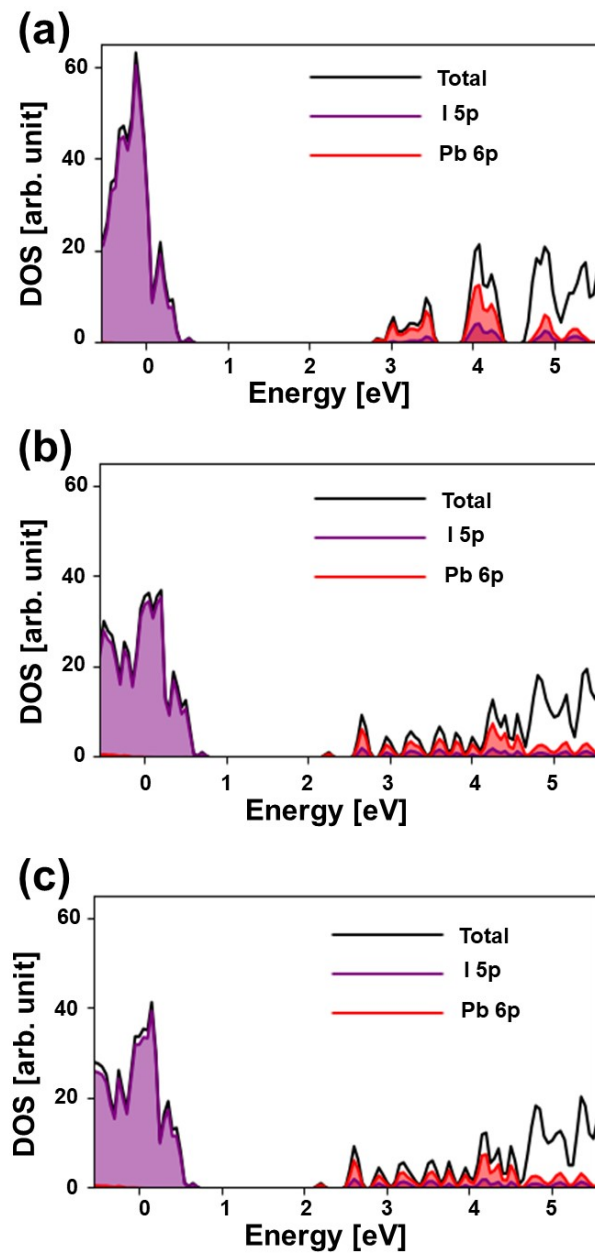


Fig. S5 Calculated total and partial density of states (PDOS) of DDAPbI₄ within: (a) GGA approximation without SOC, core electrons represented by scalar-relativistic pseudopotentials, (b) GGA approximation with SOC, using projected augmented wave functions, (c) GGA approximation with SOC including London dispersion, using projected augmented wave functions.

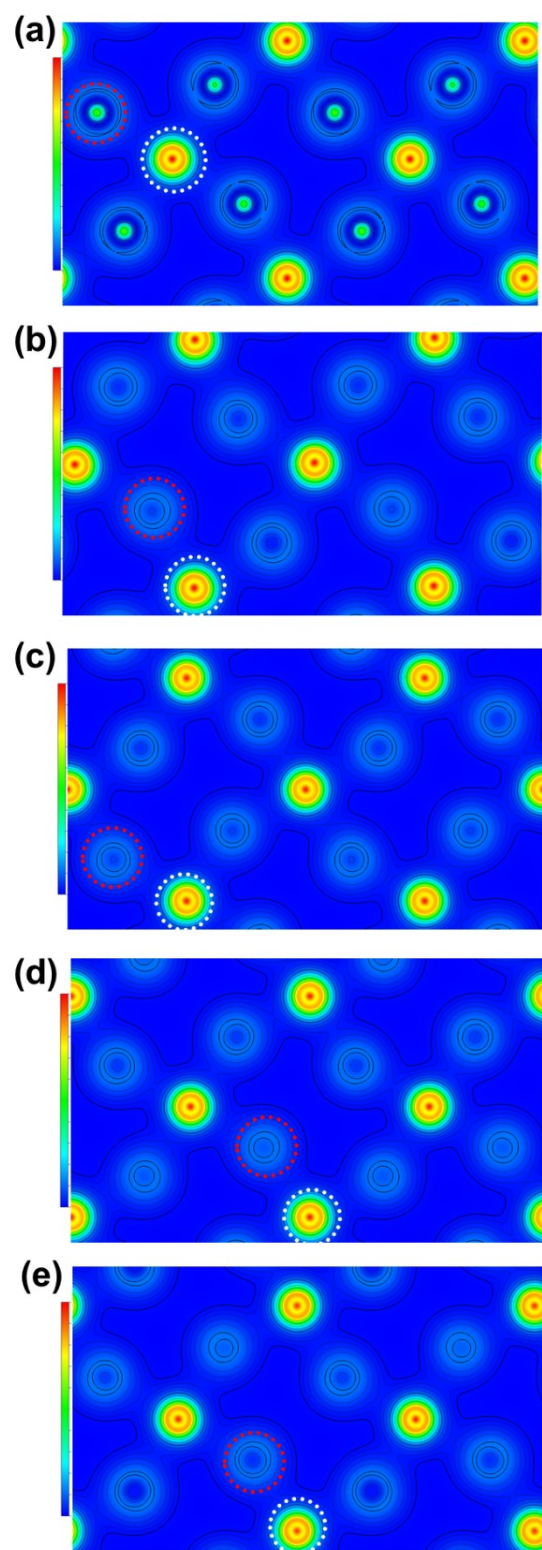


Fig. S6 Charge density plots within the inorganic plane for (a) MAPbI_3 , (b) BDAPbI_4 , (c) HDAPbI_4 , (d) ODAPbI_4 , and (e) DDAPbI_4 . The circles with white represent the lead atom and the circles with red represent the iodine atoms. A more covalent bond in between Pb and I for MAPbI_3 can be observed compared to layered perovskite.

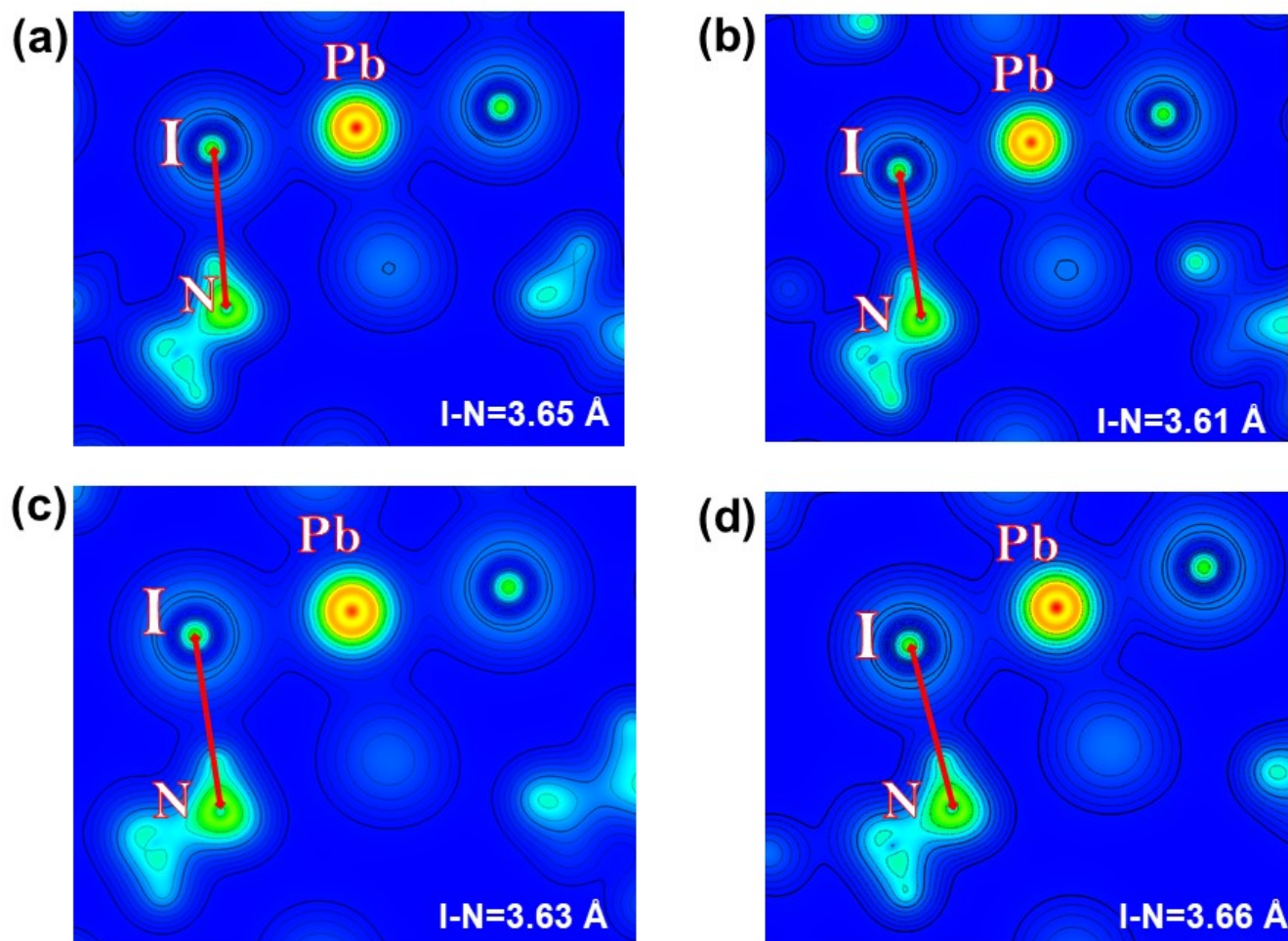


Fig. S7 Charge density plots in between the inorganic plane and organic cation for (a) BDAPbI₄, (b) HDAPbI₄, (c) ODAPbI₄, and (d) DDAPbI₄.